



## P-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY					
V <sub>DS</sub> (V)	$R_{DS(on)}(\Omega)$	I <sub>D</sub> (A)			
- 30	0.0068 at V <sub>GS</sub> = - 10 V	- 22			

### **FEATURES**

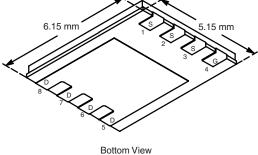
- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET<sup>®</sup> Power MOSFETs
- New Low Thermal Resistance PowerPAK<sup>®</sup>
   Package with Low 1.07 mm Profile





### **APPLICATIONS**

- · Battery and Load Switching
  - Notebook Computers
  - Notebook Battery Packs

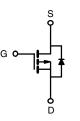


PowerPAK SO-8

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Ordering Information: Si7459DP-T1-E3 (Lead (Pb)-free)

Si7459DP-T1-GE3 (Lead (Pb)-free and Halogen-free)



P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS	T <sub>A</sub> = 25 °C, unles	ss otherwise r	noted		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V <sub>DS</sub>	- 30		V
Gate-Source Voltage		V <sub>GS</sub>	± 25		
Continuous Drain Current /T 150°C\8	T <sub>A</sub> = 25 °C	I <sub>D</sub>	- 22	- 13	
Continuous Drain Current (T <sub>J</sub> = 150°C) <sup>a</sup>	T <sub>A</sub> = 70 °C		- 17	- 10	Α
Pulsed Drain Current		I <sub>DM</sub>	- 60		A
Continuous Source Current (Diode Conduction) <sup>a</sup>		I <sub>S</sub>	- 4.5	- 1.6	
Marrian Danier Disable dia a	T <sub>A</sub> = 25 °C	P <sub>D</sub>	5.4	1.9	W
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70 °C	ט י	3.4	1.2	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C
Soldering Recommendations (Peak Temperature)b,c			260		C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum lunction to Ambienta	t ≤ 10 s	R <sub>thJA</sub>	18	23	
Maximum Junction-to-Ambient <sup>a</sup>	Steady State	' 'thJA	52	65	°C/W
Maximum Junction-to-Case (Drain)	Steady State	R <sub>thJC</sub>	1.0	1.5	

#### Notes

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile (<a href="https://www.vishay.com/ppg?73257">www.vishay.com/ppg?73257</a>). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

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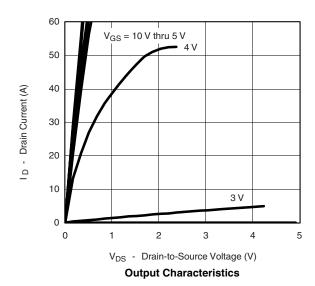
<b>SPECIFICATIONS</b> $T_J = 25$ °C	C, unless	otherwise noted				
Parameter	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Static						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = -250 \mu A$	- 1.0		- 3.0	V
Gate-Body Leakage	lass	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 25 \text{ V}$			± 200	
Zava Cata Valtaga Drain Current	1	V <sub>DS</sub> = - 30 V, V <sub>GS</sub> = 0 V			- 1	μΑ
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = - 30 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 70 °C			- 10	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} = -5 \text{ V}, V_{GS} = -10 \text{ V}$	- 30			Α
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = - 10 V, I <sub>D</sub> = - 22 A		0.0056	0.0068	Ω
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = - 15 V, I <sub>D</sub> = - 22 A		50		S
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	I <sub>S</sub> = - 2.9 A, V <sub>GS</sub> = 0 V		- 0.71	- 1.1	V
Dynamic <sup>b</sup>						
Total Gate Charge	$Q_g$			113	170	
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = -15 \text{ V}, V_{GS} = -10 \text{ V}, I_{D} = -22 \text{ A}$		17		nC
Gate-Drain Charge	$Q_{gd}$			32.5		
Turn-On Delay Time	t <sub>d(on)</sub>			25	40	
Rise Time	t <sub>r</sub>	$V_{DD}$ = - 15 V, $R_L$ = 15 $\Omega$		20	30	20
Turn-Off Delay Time	t <sub>d(off)</sub>	$\text{I}_\text{D}\cong$ - 1 A, $\text{V}_\text{GEN}$ = - 10 V, $\text{R}_g$ = 6 $\Omega$		180	270	ns
Fall Time	t <sub>f</sub>			130	200	
Gate Resistance	$R_g$			4		Ω
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	$I_F = -2.9 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}$		100	150	ns

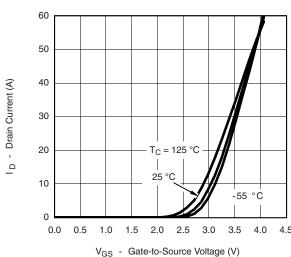
### Notes:

- a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





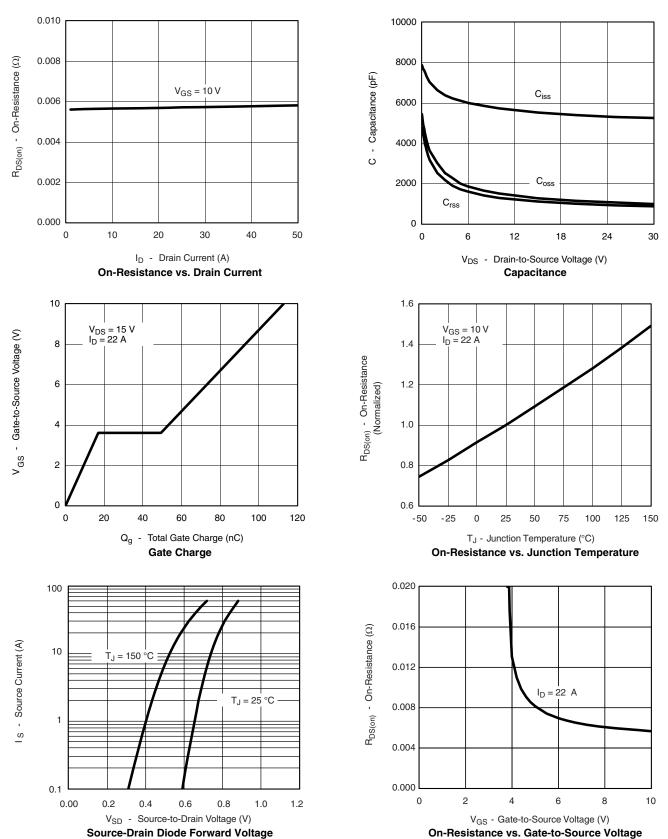
**Transfer Characteristics** 







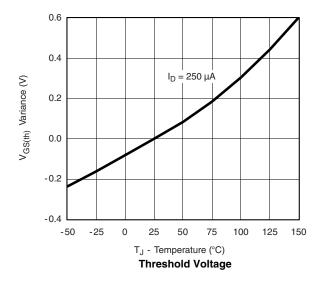
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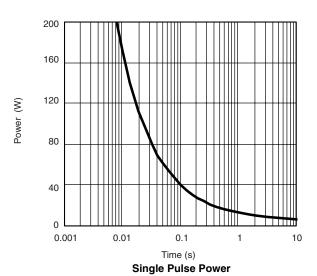


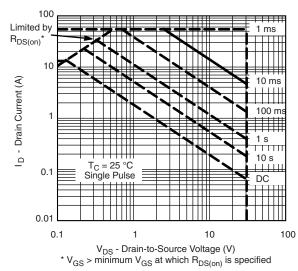
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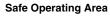
# VISHAY

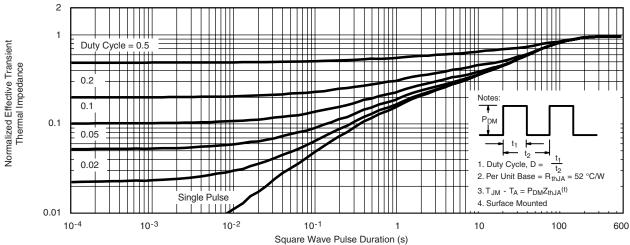
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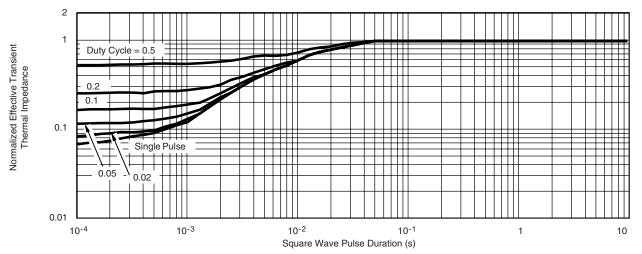




Normalized Thermal Transient Impedance, Junction-to-Ambient



## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



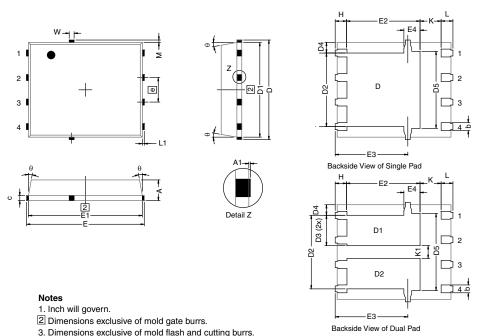
Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="https://www.vishay.com/ppg?72631">www.vishay.com/ppg?72631</a>.



DWG: 5881

# PowerPAK® SO-8, (Single/Dual)

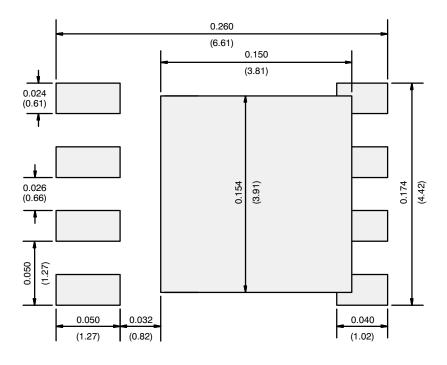


		MILLIMETERS		INCHES				
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.		
Α	0.97	1.04	1.12	0.038	0.041	0.044		
A1		-	0.05	0	-	0.002		
b	0.33	0.41	0.51	0.013	0.016	0.020		
С	0.23	0.28	0.33	0.009	0.011	0.013		
D	5.05	5.15	5.26	0.199	0.203	0.207		
D1	4.80	4.90	5.00	0.189	0.193	0.197		
D2	3.56	3.76	3.91	0.140	0.148	0.154		
D3	1.32	1.50	1.68	0.052	0.059	0.066		
D4		0.57 typ.			0.0225 typ.			
D5		3.98 typ.			0.157 typ.			
E	6.05	6.15	6.25	0.238	0.242	0.246		
E1	5.79	5.89	5.99	0.228	0.232	0.236		
E2 (for AL product)	3.30	3.48	3.66	0.130	0.137	0.144		
E2 (for other product)	3.48	3.66	3.84	0.137	0.144	0.151		
E3	3.68	3.78	3.91	0.145	0.149	0.154		
E4 (for AL product)		0.58 typ.		0.023 typ.				
E4 (for other product)		0.75 typ.		0.030 typ.				
е	1.27 BSC			0.050 BSC				
K (for AL product)	1.45 typ.			0.057 typ.				
K (for other product)	1.27 typ.			0.050 typ.				
K1	0.56	-	-	0.022	-	-		
Н	0.51	0.61	0.71	0.020	0.024	0.028		
L	0.51	0.61	0.71	0.020	0.024	0.028		
L1	0.06	0.13	0.20	0.002	0.005	0.008		
θ	0°	-	12°	0°	-	12°		
W	0.15	0.25	0.36	0.006	0.010	0.014		
М	0.125 typ.			0.005 typ.				

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### RECOMMENDED MINIMUM PADS FOR PowerPAK® SO-8 Single



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE



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